Am27S33/27S33A

Advanced Micro **Devices**

4,096-Bit (1024x4) Bipolar PROM

DISTINCTIVE CHARACTERISTICS

- High speed
 Highly reliable, ultra-fast programming Platinum-Silicide fuses
- High programming yield

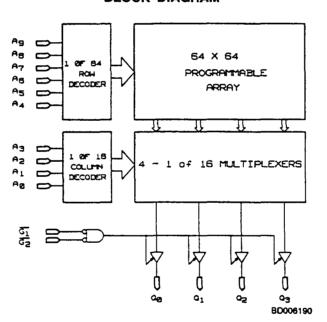
- Low-current PNP inputs
- High-current open-collector and three-state outputs
- Fast chip select

GENERAL DESCRIPTION

The Am27S33 (1024 words by 4 bits) is a Schottky TTL Programmable Read-Only Memory (PROM).

This device is available in three-state (Am27S33) output versions. These outputs are compatible with low-power Schotkky bus standards capable of satisfying the requirements of a variety of microprogrammable controls, mapping functions, code conversion, or logic replacement. Easy word-depth expansion is facilitated by active LOW ($\overline{G_1}$ & $\overline{G_2}$) output enables.

BLOCK DIAGRAM

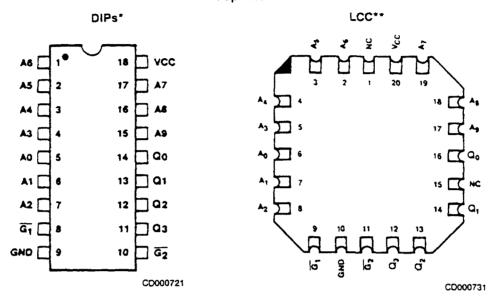


PRODUCT SELECTOR GUIDE

Three-State Part Number	Am27	7 533A	Am2	Am27S33		
Address Access Time	35 ns	45 ns	55 ns	70 ns		
Operating Range	С	М	С	м		

Publication # Rev. Amendment 03226 D /0 Issue Date: January 1989

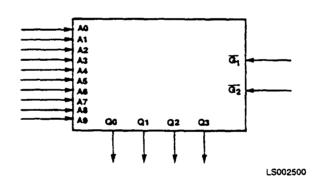
CONNECTION DIAGRAMS Top View



- *Also available in 18-pin Flatpack. Pinout identical to DIPs. **Also available in a 20-pin square PLCC. Pinout identical to LCC.

Note: Pin 1 is marked for orientation.

LOGIC SYMBOL

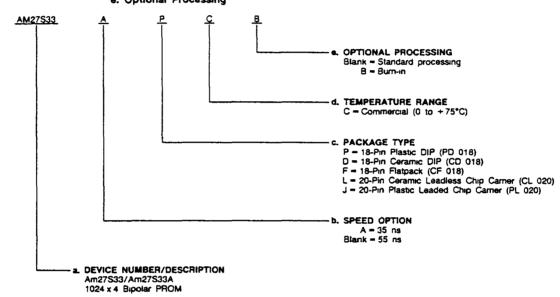


ORDERING INFORMATION

Standard Products

AMD standard products are available in several packages and operating ranges. The order number (Valid Combination) is formed by a combination of: a. Device Number

- b. Speed Option (if applicable)
- c. Package Type d. Temperature Range
- e. Optional Processing



	Valid	Cai	mbina	ation	8		_
AM27S33						DCB, LCB,	_
AM27533	Δ		ICE	ruo.	LC,	LCO, J	U,

Valid Combinations

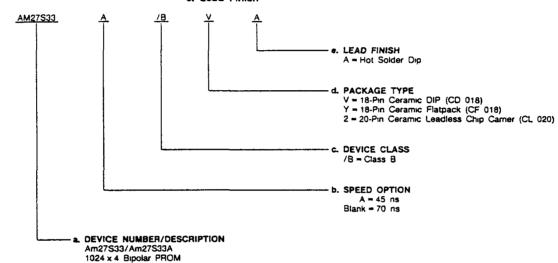
Valid Combinations list configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations, to check on newly released combinations, and to obtain additional data on AMD's standard military grade readucts. products.

MILITARY ORDERING INFORMATION

APL Products

AMD products for Aerospace and Defense applications are available in several packages and operating ranges. APL (Approved Products List) products are fully compliant with MIL-STD-883C requirements. The order number (Valid Combination) for APL products is formed by a combination of: a. Device Number

- b. Speed Option (if applicable)
- c. Device Class
- d. Package Type
- e. Lead Finish



Valld	Combinations	
AM27S33	/BVA, /BYA,	
AM27S33A	/B2A	

Valid Combinations

Valid Combinations list configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations or to check for newly released valid combinations.

Group A Tests

Group A tests consist of Subgroups 1, 2, 3, 7, 8, 9, 10, 11.

MILITARY BURN-IN

Military burn-in is in accordance with the current revision of MIL-STD-883, Test Method 1015, Conditions A through E. Test conditions are selected at AMD's option.

PIN DESCRIPTION

A₀ - A₉ Address Inputs

The 10-bit field presented at the address inputs selects one of 1024 memory locations to be read from.

Q₀-Q₃ Data Output Port

The outputs whose state represents the data read from the selected memory locations.

G1,G2 Output Enable

Provides direct control of the Q-output buffers. Outputs disabled forces all open-collector outputs to an OFF state

and all three-state outputs to a floating or high-impedance state.

Enable =
$$\overline{G_1} \cdot \overline{G_2}$$

Disable = $\overline{G_1} \cdot \overline{G_2}$

$= G_1 \ + \ G_2$ V_{CC} Device Power Supply Pin

The most positive of the logic power supply pins.

GND Device Power Supply Pin

The most negative of the logic power supply pins.

-- 4.

ABSOLUTE MAXIMUM RATINGS

Storage Temperature65 to +150°C
Ambient Temperature with
Power Applied
Supply Voltage
DC Voltage Applied to Outputs
(Except During Programming)0.5 V to +VCCMax.
DC Voltage Applied to Outputs
During Programming 21 V
Output Current into Outputs During
Programming (Max Duration of 1 sec) 250 mA
DC Input Voltage05 V to +55 V
DC Input Current30 mA to +5 mA

Stresses above those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to absolute maximum ratings for extended periods may affect device reliability.

OPERATING RANGES

Commercial (C) Devices Ambient Temperature (T _A) Supply Voltage (V _{CC})	0 to +75°C +475 V to +525 V
Military (M) Devices*	
Case Temperature (T _C)	55 to +125°C
Supply Voltage (VCC)	+4.5 V to +55 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

*Military Product 100% tested at $T_C = +25$ °C, +125°C, and -55°C.

DC CHARACTERISTICS over operating ranges unless otherwise specified (for APL Products, Group A, Subgroups 1, 2, 3 are tested unless otherwise noted)

Parameter Symbol	Parameter Description	Test Conditions			Min.	Тур.	Max.	Unit	
Voн	Output HIGH Voltage	V _{CC} = Min , 1 _{OH} = -2.0 mA V _{IN} = V _{IH} or V _{IL}						٧	
VOL	Output LOW Voltage	V _{CC} = Min., I _{OL} = 16 mA V _{IN} = V _{IH} or V _{IL}					0.45	>	
VIH	Input HIGH Level		Guaranteed input logical HIGH voltage for all inputs (Note 1)					٧	
VIL	Input LOW Level		Guaranteed input logical LOW voltage for all inputs (Note 1)				0.8	٧	
lic.	Input LOW Current	VCC - Max , VIN - 0.45 V					-0 250	Αm	
Л Н	Input HIGH Current	VCC - Max., VII	N = 2.7 V	\top		25	μΑ		
ISC (Note 1)	Output Short-Circuit Current	VCC = Max., VOUT = 0.0 V (Note 2)					-90	mA	
laa	Power Supply Current		All inputs = GND.				140	mA.	
lcc	Power Supply Current	VCC - Max.		MIL			145	πА	
Vı	Input Clamp Voltage	VCC = Min., IN	=-18 mA				-12	V	
				Vo = Vcc			40		
CEX	Output Leakage Current	V _{CC} = Max. V _{G1} = 2.4 V	(Note 1)	Vo = 2.4 V			40	μA	
				VO = 0.4 V			-40		
CIN	Input Capacitance	V _{IN} = 2.0 V @ f = 1 MHz (Note 3) V _{CC} = 5 V. T _A = 25°C V _{OUT} = 2.0 V @ f = 1 MHz (Note 3) V _{CC} = 5 V. T _A = 25°C				5		ρF	
COUT	Output Capacitance					8			

Notes: 1. V_{IL} and V_{IH} are input conditions of output tests and are not themselves directly tested. V_{IL} and V_{IH} are absolute voltages with respect to device ground and include all overshoots due to system and/or tester noise. On not attempt to test these values without suitable equipment.

2. Not more than one output should be shorted at a time. Duration of the short circuit should not be more than one second.

3. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.

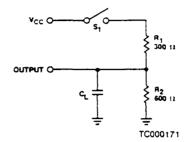
SWITCHING CHARACTERISTICS over operating ranges unless otherwise specified (for APL Products, Group A, Subgroups 9, 10, 11 are tested unless otherwise noted*)

				Am27S33A				Am27S33				
	1	\		COM'L MIL		IIL	COM'L		MIL		ĺ	
No.	Parameter Symbol	Parameter Description		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Unit
1	TAVQV	Address Valid to Output Valid Access Time	`		35		45		55		70	ns.
2	TGVQZ	Delay from Output Enable Valid to Output Hi-Z			20		25		25		30	ns
3	TGVQV	Delay from Output Enable Valid to Output Valid			20		25		25		30	ns

See also Switching Test Circuit.

Notes: 1. Tests are performed with input transition time of 5 ns or less, timing reference levels of 1.5 V, and input pulse levels of 0 to 3.0 V. *Subgroups 7 and 8 apply to functional tests.

SWITCHING TEST CIRCUIT

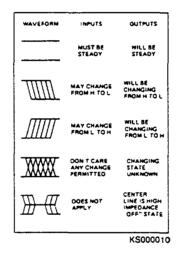


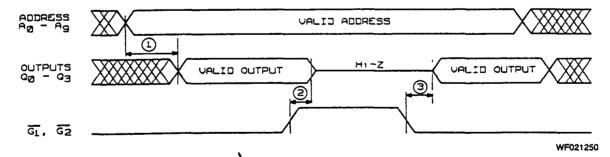
Notes. 1 TAVQV is tested with switch S₁ closed and C_L = 50 pF

2 For three-state outputs, TGVQV is tested with C_L = 50 pF to the 1.5 V level; S₁ is open for high impedance to HIGH tests and closed for high impedance to LOW tests TGVQZ is tested with C_L = 5 pF HIGH to high-impedance tests are made with S₁ open to an output voltage of steady state HIGH -0.5 V; LOW to high-impedance tests are made with S₁ closed to the steady state LOW +0.5 V level.

SWITCHING WAVEFORMS

KEY TO SWITCHING WAVEFORM





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